

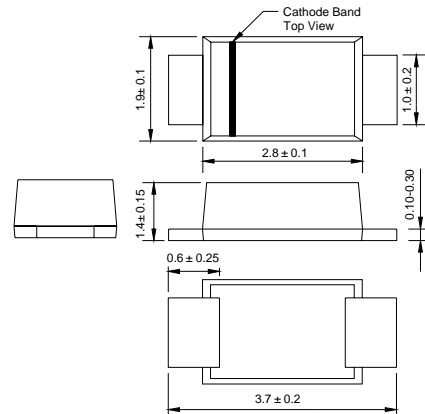
Features

- Glass passivated device
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Surge Overload Rating to 2.5 A Peak
- Low Power Loss
- Ultra-Fast Recovery Time
- Plastic Case Material has UL Flammability
- Classification Rating 94V-O

Mechanical Data

- Case: SOD-123FL, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.01 grams (approx.)
- **Lead Free: For RoHS / Lead Free Version**

SOD - 123FL



Dimensions in millimeters

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	FR	FR	FR	FR	FR	FR	FR	UNITS
		101	102	103	104	105	106	107	
Device marking code		F1	F2	F3	F4	F5	F6	F7	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{VRM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	800	V
Average Rectified Output Current @T _L = 100°C	I _O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	25							A
Forward Voltage @I _F = 1.0A	V _{FM}	1.3							V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	10 500							μA
Reverse Recovery Time (Note 2)	t _{rr}	150			250	500			nS
Typical Junction Capacitance (Note 2)	C _j	4							pF
Typical Thermal Resistance (Note 3)	R _{θJL}	180							°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150							°C

- Note: 1. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
 3. Mounted on P.C. Board with 8.0mm² land area.

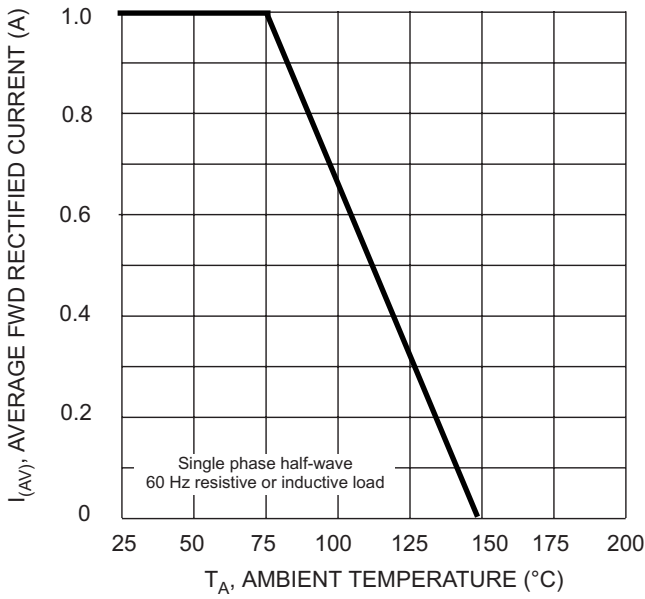


Fig. 1 Forward Derating Curve

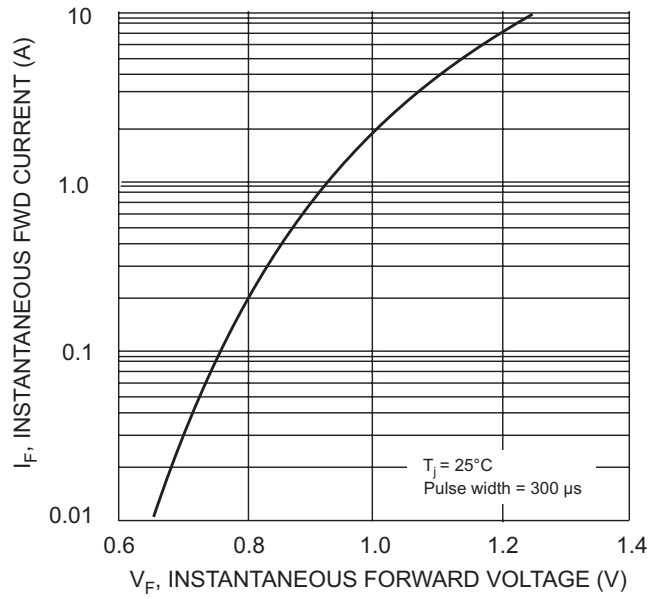


Fig. 2 Typical Forward Characteristics

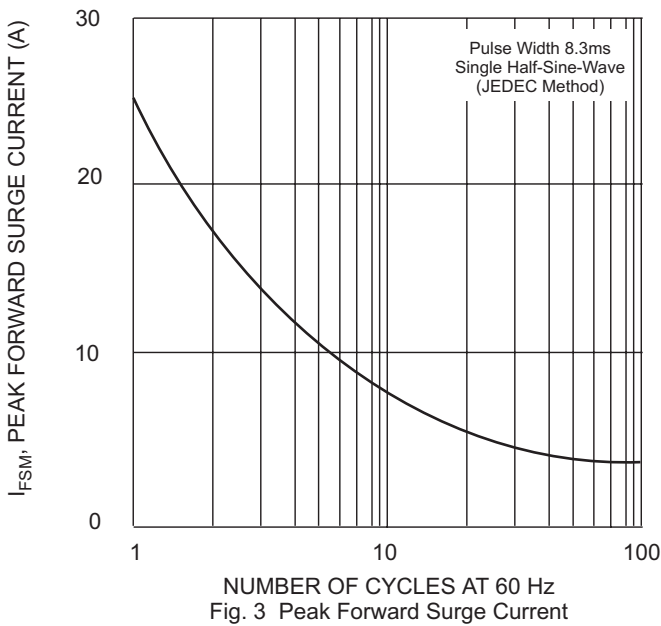


Fig. 3 Peak Forward Surge Current

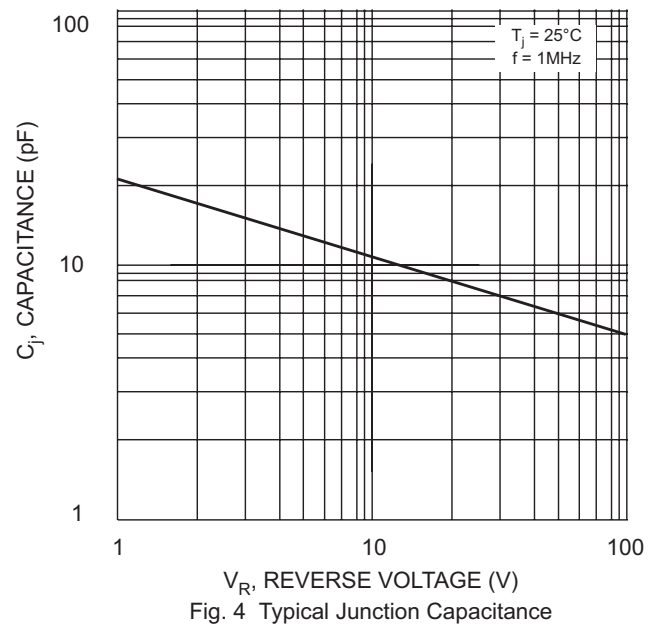
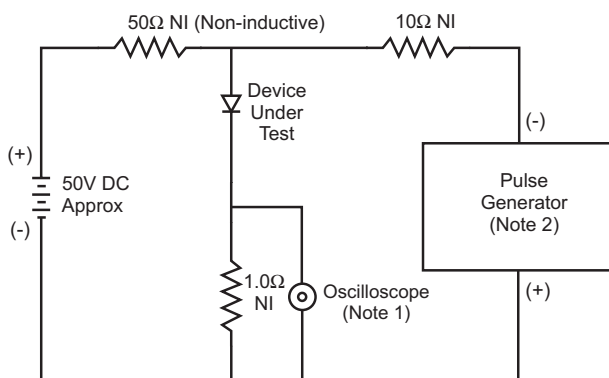
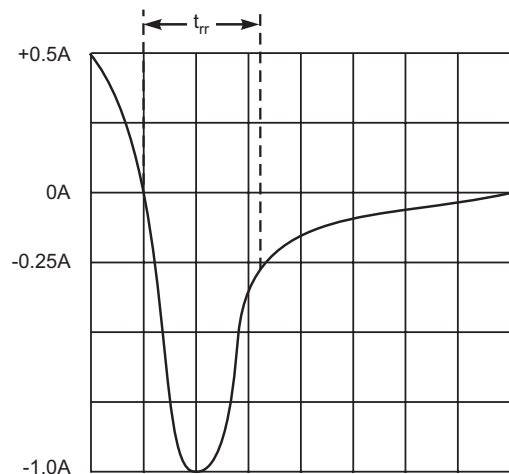


Fig. 4 Typical Junction Capacitance



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit